

# S-8239A Series

# OVERCURRENT MONITORING IC FOR MULTI-SERIAL-CELL PACK

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The S-8239A Series is an overcurrent monitoring IC for multi-serial-cell pack including high-accuracy voltage detection circuits and delay circuits.

The S-8239A Series is suitable for protection of lithium-ion / lithium polymer rechargeable battery packs from overcurrent.

### ■ Features

• Built-in high-accuracy voltage detection circuit

Overcurrent 1 detection voltage\*1 0.04 V to 0.30 V (10 mV step) Accuracy  $\pm$ 15 mV Overcurrent 2 detection voltage 0.1 V to 0.7 V (100 mV step) Accuracy  $\pm$ 100 mV Overcurrent 3 detection voltage 1.2 V (Fixed) Accuracy  $\pm$ 300 mV

• Built-in three-step overcurrent detection circuit: Overcurrent 1, overcurrent 2, overcurrent 3

• Overcurrent 3 detection function is selectable: Available, unavailable

• UVLO (under voltage lock out) function

UVLO detection voltage 2.0 V (Fixed) Accuracy ±100 mV

• High-withstand voltage: VM pin, DO pin: Absolute maximum rating 28 V

• Delay times are generated only by an internal circuit (External capacitors are unnecessary).

• Low current consumption

 $\begin{array}{ll} \text{During normal operation:} & 7.0 \ \mu\text{A max.} \\ \text{During UVLO operation:} & 6.0 \ \mu\text{A max.} \\ \end{array}$ 

Output logic: Active "L", Active "H"
 Wide operation temperature range: Ta = -40°C to +85°C

• Lead-free (Sn 100%), halogen-free

\*1. Overcurrent 1 detection voltage ≤ 0.06 V should be satisfied in the case of overcurrent 2 detection voltage = 0.1 V. Overcurrent 1 detection voltage ≤ 0.85 × overcurrent 2 detection voltage – 0.05 V should be satisfied in the case of overcurrent 2 detection voltage ≥ 0.2 V.

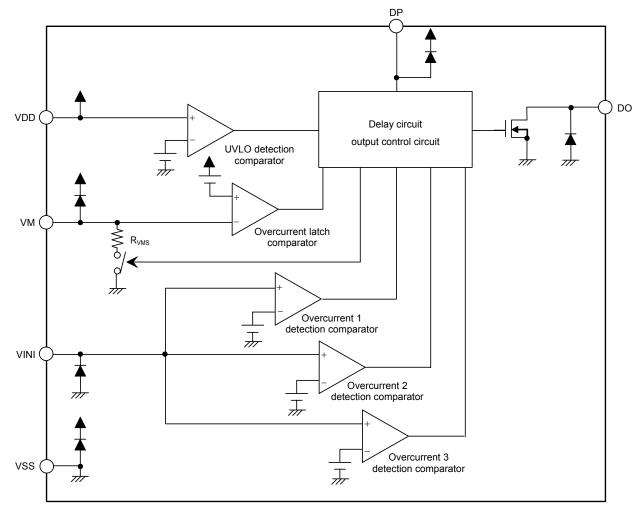
## ■ Applications

- Lithium-ion rechargeable battery pack
- · Lithium polymer rechargeable battery pack

#### ■ Package

• SOT-23-6

## **■** Block Diagram

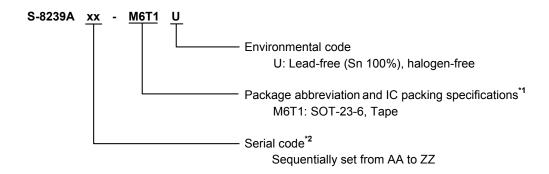


Remark All the diodes shown in the figure are parasitic diodes.

Figure 1

## **■** Product Name Structure

## 1. Product name



- \*1. Refer to the tape drawing.
- \*2. Refer to "3. Product name list".

## 2. Package

**Table 1 Package Drawing Codes** 

Package Name	Dimension	Tape	Reel
SOT-23-6	MP006-A-P-SD	MP006-A-C-SD	MP006-A-R-SD

### 3. Product name list

Table 2

Product Name	Overcurrent 1 Detection Voltage [V <sub>DIOV1</sub> ]	Overcurrent 2 Detection Voltage [V <sub>DIOV2</sub> ]	Overcurrent 1 Detection Delay Time [tDIOV1]	Overcurrent 2 Detection Delay Time [tDIOV2]	Overcurrent 3 Detection Function	Output Logic
S-8239AAA-M6T1U	0.08 V	0.4 V	1150 ms	1.12 ms	Unavailable	Active "L"
S-8239AAB-M6T1U	0.10 V	0.5 V	1150 ms	0.28 ms	Unavailable	Active "L"
S-8239AAC-M6T1U	0.10 V	0.3 V	18.0 ms	0.28 ms	Unavailable	Active "L"
S-8239AAD-M6T1U	0.10 V	0.2 V	290 ms	0.56 ms	Unavailable	Active "L"
S-8239AAE-M6T1U	0.10 V	0.7 V	18.0 ms	0.56 ms	Unavailable	Active "L"
S-8239AAF-M6T1U	0.04 V	0.3 V	4600 ms	0.28 ms	Unavailable	Active "L"
S-8239AAG-M6T1U	0.10 V	0.2 V	1150 ms	1.12 ms	Available	Active "L"
S-8239AAH-M6T1U	0.06 V	0.1 V	290 ms	0.56 ms	Unavailable	Active "L"
S-8239AAI-M6T1U	0.10 V	0.3 V	290 ms	0.28 ms	Unavailable	Active "L"
S-8239AAJ-M6T1U	0.11 V	0.3 V	4600 ms	2.24 ms	Available	Active "L"
S-8239AAK-M6T1U	0.10 V	0.3 V	290 ms	1.12 ms	Available	Active "H"

**Remark** Contact our sales office for the products with detection voltage value other than those specified above.

## **■** Pin Configuration

## 1. SOT-23-6



Figure 2

### Table 3

Pin No.	Symbol	Description
1	VINI	Voltage detection pin between VINI pin and VSS pin (Overcurrent detection pin)
2	VM	Overcurrent latch pin
3	DO	Connection pin of discharge control FET gate
4	DP*1	Test pin for delay time measurement
5	VDD	Input pin for positive power supply
6	VSS	Input pin for negative power supply

**<sup>\*1.</sup>** The DP pin should be open.

## ■ Absolute Maximum Ratings

Table 4

(Ta = +25°C unless otherwise specified)

Item	Symbol	Applied pin	Absolute Maximum Rating	Unit
Input voltage between VDD pin and VSS pin	V <sub>DS</sub>	VDD	$V_{SS}-0.3$ to $V_{SS}+12$	V
VM pin input voltage	$V_{VM}$	VM	$V_{DD}-28 \ to \ V_{DD}+0.3$	V
VINI pin input voltage	$V_{VINI}$	VINI	$V_{SS}-0.3$ to $V_{SS}+12$	V
DO pin output voltage	$V_{DO}$	DO	$V_{SS} - 0.3$ to $V_{SS} + 28$	V
Power dissipation	P <sub>D</sub>	_	650 <sup>*1</sup>	mW
Operation ambient temperature	T <sub>opr</sub>	_	-40 to +85	°C
Storage temperature	T <sub>stg</sub>	_	−55 to +125	°C

<sup>\*1.</sup> When mounted on board

[Mounted board]

(1) Board size: 114.3 mm  $\times$  76.2 mm  $\times$  t1.6 mm (2) Board name: JEDEC STANDARD51-7

## Caution 1. The DP pin should be open.

2. The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

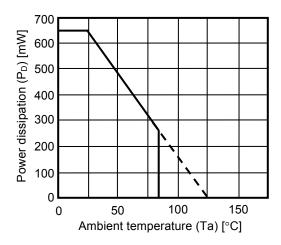


Figure 3 Power Dissipation of Package (When Mounted on Board)

## **■** Electrical Characteristics

1. Ta = +25°C

Table 5

(Ta = +25°C unless otherwise specified)

				(1a -	TZ3 C ui	11033	otnerwise s	pecified)
Item	Symbol	Condition	Min.	Тур.	Max.	Unit	Test Condition	Test Circuit
Detection Voltage								
Overcurrent 1 detection voltage	$V_{\text{DIOV1}}$	-	V <sub>DIOV1</sub> - 0.015	$V_{\text{DIOV1}}$	V <sub>DIOV1</sub> + 0.015	V	1	1
Overcurrent 2 detection voltage*1	V <sub>DIOV2</sub>	-	V <sub>DIOV2</sub> - 0.100	$V_{\text{DIOV2}}$	V <sub>DIOV2</sub> + 0.100	V	1	1
Overcurrent 3 detection voltage	V <sub>DIOV3</sub>	Overcurrent 3 detection function "available"	0.90	1.20	1.50	V	1	1
UVLO detection voltage	$V_{\text{UVLO}}$	_	1.90	2.00	2.10	V	1	1
Release Voltage	•						•	
Overcurrent release voltage	$V_{RIOV}$	V <sub>DD</sub> criteria, V <sub>DD</sub> = 3.5 V	0.7	1.2	1.5	V	1	1
Input Voltage, Operation Voltage		-			<u> </u>		1	
Operation voltage between VDD pin and VSS pin	V <sub>DSOP</sub>	Output logic is determined*2	1.5	-	8	V	-	-
Current Consumption								
Current consumption during normal operation	I <sub>OPE</sub>	V <sub>DD</sub> = 3.5 V, V <sub>VM</sub> = 0 V	1.0	3.5	7.0	μА	2	2
Current consumption during UVLO operation	I <sub>UVLO</sub>	V <sub>DD</sub> = V <sub>VM</sub> = 1.5 V	0.7	3.0	6.0	μА	2	2
Internal Resistance								
Internal resistance between VM pin and VSS pin	R <sub>VMS</sub>	$V_{DD} = V_{VM} = 3.5 \text{ V}$	210	300	390	kΩ	3	3
Output Resistance (Active "L")								
DO pin resistance "L"	R <sub>DOL</sub>	$V_{DD} = V_{VINI} = 3.5 \text{ V}, V_{DO} = 0.5 \text{ V}$	2.5	5	10	kΩ	4	4
Output Resistance (Active "H")								
DO pin resistance "L"	R <sub>DOL</sub>	$V_{DD} = 3.5 \text{ V}, V_{VINI} = 0 \text{ V}$ $V_{DO} = 0.5 \text{ V}$	2.5	5	10	kΩ	4	4
Delay Time								
Overcurrent 1 detection delay time	t <sub>DIOV1</sub>	-	$t_{DIOV1} \times 0.6$	t <sub>DIOV1</sub>	$t_{DIOV1} \times 1.4$	ms	5	5
Overcurrent 2 detection delay time	t <sub>DIOV2</sub>	-	$t_{DIOV2} \times 0.6$	t <sub>DIOV2</sub>	$t_{DIOV2} \times 1.4$	ms	5	5
Overcurrent 3 detection delay time	t <sub>DIOV3</sub>	Overcurrent 3 detection function "available"	168	280	392	μS	5	5
UVLO detection delay time	t <sub>UVLO</sub>	-	2.94	4.90	6.86	s	5	5
*1 Even if everourrent 1 detection		1011			oomo roi			or than

<sup>\*1.</sup> Even if overcurrent 1 detection voltage and overcurrent 2 detection voltage are in the same range,  $V_{DIOV1}$  is lower than  $V_{DIOV2}$ .

**<sup>\*2.</sup>** It indicates that DO pin output logic is determined.

## 2. Ta = $-40^{\circ}$ C to $+85^{\circ}$ C<sup>\*1</sup>

Table 6

(Ta = -40°C to +85°C<sup>\*1</sup> unless otherwise specified) Test Test Unit Item Symbol Condition Min. Typ. Max. Circuit Condition **Detection Voltage**  $V_{DIOV1}$  $V_{DIOV1}$ Overcurrent 1 detection voltage  $V_{DIOV1}$ ٧ 1 1  $V_{DIOV1}$ - 0.021 + 0.021  $V_{\text{DIOV2}}$  $V_{DIOV2}$ Overcurrent 2 detection voltage\*2  $V_{\text{DIOV2}} \\$  $V_{\text{DIOV2}}$ ٧ 1 1 - 0.130 + 0.130 Overcurrent 3 detection function Overcurrent 3 detection voltage 0.70 1.20 1.70 ٧ 1 1  $V_{DIOV3}$ available" UVLO detection voltage 1.85 2.00 2.15 V 1 1  $V_{\text{UVLO}}$ Release Voltage V Overcurrent release voltage  $V_{\text{RIOV}}$  $V_{DD}$  criteria,  $V_{DD}$  = 3.5 V 0.5 1.2 1.7 1 1 Input Voltage, Operation Voltage Operation voltage between Output logic is determined\*3 VDSOP 1.5 8 V VDD pin and VSS pin **Current Consumption** Current consumption during  $V_{DD} = 3.5 \text{ V}, V_{VM} = 0 \text{ V}$ 0.7 3.5 8.0 2 2 **IOPE** μΑ normal operation Current consumption during  $V_{DD} = V_{VM} = 1.5 \text{ V}$ 2 2 **I**UVLO 0.5 3.0 7.0 μΑ UVLO operation **Internal Resistance** Internal resistance between  $R_{\text{VMS}}$  $V_{DD} = V_{VM} = 3.5 \text{ V}$ 150 300 450  $k\Omega$ 3 3 VM pin and VSS pin Output Resistance (Active "L")  $V_{DD} = V_{VINI} = 3.5 \text{ V}, V_{DO} = 0.5 \text{ V}$ 1.2 DO pin resistance "L" **R**<sub>DOL</sub> 5 15  $k\Omega$ 4 4 Output Resistance (Active "H")  $V_{DD} = 3.5 \text{ V}, V_{VINI} = 0 \text{ V}$  $R_{\text{DOL}}$ DO pin resistance "L" 1.2 5 15  $k\Omega$ 4 4  $V_{DO} = 0.5 \text{ V}$ **Delay Time** Overcurrent 1 detection delay  $t_{\text{DIOV1}}$  $t_{\text{DIOV1}} \\$ 5 5  $t_{DIOV1}$ t<sub>DIOV1</sub> ms × 0.2 × 1.8 time Overcurrent 2 detection delay t<sub>DIOV2</sub>  $t_{\text{DIOV2}}$ 5 5  $t_{\text{DIOV2}}$  $t_{DIOV2}$ ms  $\times$  0.2 × 1.8 time Overcurrent 3 detection delay Overcurrent 3 detection function 56 280 504 μS 5 5  $t_{DIOV3}$ "available" time UVLO detection delay time tuvlo 0.98 4.90 8.82 s 5 5

**<sup>\*1.</sup>** Since products are not screened at high and low temperatures, the specification for this temperature range is guaranteed by design, not tested in production.

<sup>\*2.</sup> Even if overcurrent 1 detection voltage and overcurrent 2 detection voltage are in the same range, V<sub>DIOV2</sub> is lower than V<sub>DIOV2</sub>.

<sup>\*3.</sup> It indicates that DO pin output logic is determined.

#### ■ Test Circuits

Caution Unless otherwise specified, the output voltage levels "H" and "L" at the DO pin (V<sub>DO</sub>) are judged by the threshold voltage (1.0 V) of the N-channel FET. Judge the DO pin level with respect to V<sub>SS</sub>.

# 1. Overcurrent 1 detection voltage, overcurrent 2 detection voltage, overcurrent release voltage, UVLO detection voltage

(Test condition 1, test circuit 1)

#### 1. 1 Active "L"

The overcurrent 1 detection voltage ( $V_{DIOV1}$ ) is defined as the voltage V2 whose delay time for changing  $V_{DO}$  from "H" to "L" lies between the minimum and the maximum value of the overcurrent 1 detection delay time after the voltage V2 is increased instantaneously (within 10  $\mu$ s) from the set conditions of V1 = V3 = 3.5 V, V2 = 0 V.

The overcurrent 2 detection voltage ( $V_{DIOV2}$ ) is defined as the voltage V2 whose delay time for changing  $V_{DO}$  from "H" to "L" lies between the minimum and the maximum value of the overcurrent 2 detection delay time after the voltage V2 is increased instantaneously (within 10  $\mu$ s) from the set conditions of V1 = V3 = 3.5 V, V2 = 0 V.

The overcurrent release voltage ( $V_{RIOV}$ ) is defined as the voltage V3 at which  $V_{DO}$  goes from "L" to "H" after decreasing V2 to 0 V and the voltage V3 is increased gradually from the set conditions of V1 = V2 = 3.5 V, V3 = 0 V.

The UVLO detection voltage ( $V_{UVLO}$ ) is defined as the voltage V1 at which  $V_{DO}$  goes from "H" to "L" after the voltages V1 and V3 are decreased gradually from the set conditions of V1 = V3 = 3.5 V, V2 = 0 V.

#### 1. 2 Active "H"

The overcurrent 1 detection voltage ( $V_{DIOV1}$ ) is defined as the voltage V2 whose delay time for changing  $V_{DO}$  from "L" to "H" lies between the minimum and the maximum value of the overcurrent 1 detection delay time after the voltage V2 is increased instantaneously (within 10  $\mu$ s) from the set conditions of V1 = V3 = 3.5 V, V2 = 0 V.

The overcurrent 2 detection voltage ( $V_{DIOV2}$ ) is defined as the voltage V2 whose delay time for changing  $V_{DO}$  from "L" to "H" lies between the minimum and the maximum value of the overcurrent 2 detection delay time after the voltage V2 is increased instantaneously (within 10  $\mu$ s) from the set conditions of V1 = V3 = 3.5 V, V2 = 0 V.

The overcurrent release voltage ( $V_{RIOV}$ ) is defined as the voltage V3 at which  $V_{DO}$  goes from "H" to "L" after decreasing V2 to 0 V and the voltage V3 is increased gradually from the set conditions of V1 = V2 = 3.5 V, V3 = 0 V.

The UVLO detection voltage ( $V_{UVLO}$ ) is defined as the voltage V1 at which  $V_{DO}$  goes from "L" to "H" after the voltages V1 and V3 are decreased gradually from the set conditions of V1 = V3 = 3.5 V, V2 = 0 V.

# 2. Overcurrent 3 detection voltage (Overcurrent 3 detection function "available") (Test condition 1, test circuit 1)

#### 2. 1 Active "L"

The overcurrent 3 detection voltage ( $V_{DIOV3}$ ) is defined as the voltage V2 whose delay time for changing  $V_{DO}$  from "H" to "L" lies between the minimum and the maximum value of the overcurrent 3 detection delay time after the voltage V2 is increased instantaneously (within 10  $\mu$ s) from the set conditions of V1 = V3 = 3.5 V, V2 = 0 V.

#### 2. 2 Active "H"

The overcurrent 3 detection voltage ( $V_{DIOV3}$ ) is defined as the voltage V2 whose delay time for changing  $V_{DO}$  from "L" to "H" lies between the minimum and the maximum value of the overcurrent 3 detection delay time after the voltage V2 is increased instantaneously (within 10  $\mu$ s) from the set conditions of V1 = V3 = 3.5 V, V2 = 0 V.

# 3. Current consumption during normal operation, current consumption during UVLO operation (Test condition 2, test circuit 2)

The current consumption during normal operation ( $I_{OPE}$ ) is the current that flows through the VDD pin ( $I_{DD}$ ) under the set conditions of V1 = 3.5 V, V2 = 0 V.

The current consumption during UVLO operation ( $I_{UVLO}$ ) is  $I_{DD}$  under the set conditions of V1 = V2 = 1.5 V.

# 4. Internal resistance between VM pin and VSS pin (Test condition 3, test circuit 3)

The internal resistance between the VM pin and the VSS pin ( $R_{VMS}$ ) is the resistance between the VM pin and the VSS pin under the set condition of V1 = V2 = V3 = 3.5 V.

## 5. DO pin resistance "L"

(Test condition 4, test circuit 4)

#### 5. 1 Active "L"

The DO pin resistance "L" (RDOL) is the DO pin resistance under the set conditions of V1 = V2 = 3.5 V, V3 = 0.5 V.

#### 5. 2 Active "H"

The DO pin resistance "L" ( $R_{DOL}$ ) is the DO pin resistance under the set conditions of V1 = 3.5 V, V2 = 0 V, V3 = 0.5 V.

## 6. Overcurrent 1 detection delay time

(Test condition 5, test circuit 5)

#### 6. 1 Active "L"

#### 6. 1. 1 $V_{DIOV2} = 0.1 V$

The overcurrent 1 detection delay time ( $t_{DIOV1}$ ) is the time period from when the voltage V2 exceeds  $V_{DIOV1}$  to when  $V_{DO}$  goes to "L", after V2 is increased to 0.08V instantaneously (within 10  $\mu$ s) under the set conditions of V1 = 3.5 V, V2 = 0 V.

#### 6. 1. 2 $V_{DIOV2} \ge 0.2 V$

The overcurrent 1 detection delay time ( $t_{DIOV1}$ ) is the time period from when the voltage V2 exceeds  $V_{DIOV1}$  to when  $V_{DO}$  goes to "L", after V2 is increased to  $V_{DIOV1}$  max. + 0.01 V instantaneously (within 10  $\mu$ s) under the set conditions of V1 = 3.5 V, V2 = 0 V.

#### 6. 2 Active "H"

### 6. 2. 1 $V_{DIOV2} = 0.1 V$

The overcurrent 1 detection delay time ( $t_{DIOV1}$ ) is the time period from when the voltage V2 exceeds  $V_{DIOV1}$  to when  $V_{DO}$  goes to "H", after V2 is increased to 0.08V instantaneously (within 10  $\mu$ s) under the set conditions of V1 = 3.5 V, V2 = 0 V.

#### 6. 2. 2 $V_{DIOV2} \ge 0.2 V$

The overcurrent 1 detection delay time ( $t_{DIOV1}$ ) is the time period from when the voltage V2 exceeds  $V_{DIOV1}$  to when  $V_{DO}$  goes to "H", after V2 is increased to  $V_{DIOV1}$  max. + 0.01 V instantaneously (within 10  $\mu$ s) under the set conditions of V1 = 3.5 V, V2 = 0 V.

## Overcurrent 2 detection delay time, UVLO detection delay time (Test condition 5, test circuit 5)

#### 7. 1 Active "L"

The overcurrent 2 detection delay time ( $t_{DIOV2}$ ) is the time period from when the voltage V2 exceeds  $V_{DIOV2}$  to when  $V_{DO}$  goes to "L", after V2 is increased to 0.9 V instantaneously (within 10  $\mu$ s) under the set conditions of V1 = 3.5 V, V2 = 0 V.

The UVLO detection delay time ( $t_{UVLO}$ ) is the time period from when the voltage V1 falls below  $V_{UVLO}$  to when  $V_{DO}$  goes to "L", after V1 is decreased to 1.8 V instantaneously (within 10  $\mu$ s) under the set conditions of V1 = 3.5 V, V2 = 0 V.

#### 7. 2 Active "H"

The overcurrent 2 detection delay time ( $t_{DIOV2}$ ) is the time period from when the voltage V2 exceeds  $V_{DIOV2}$  to when  $V_{DO}$  goes to "H", after V2 is increased to 0.9 V instantaneously (within 10  $\mu$ s) under the set conditions of V1 = 3.5 V, V2 = 0 V.

The UVLO detection delay time ( $t_{UVLO}$ ) is the time period from when the voltage V1 falls below  $V_{UVLO}$  to when  $V_{DO}$  goes to "H", after V1 is decreased to 1.8 V instantaneously (within 10  $\mu$ s) under the set conditions of V1 = 3.5 V, V2 = 0 V.

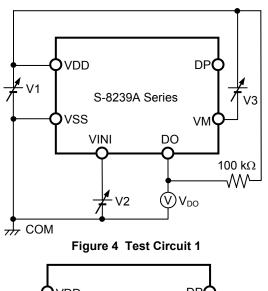
# 8. Overcurrent 3 detection delay time (Overcurrent 3 detection function "available") (Test condition 5, test circuit 5)

## 8. 1 Active "L"

The overcurrent 3 detection delay time ( $t_{DIOV3}$ ) is the time period from when the voltage V2 exceeds  $V_{DIOV3}$  to when  $V_{DO}$  goes to "L", after V2 is increased to 1.6 V instantaneously (within 10  $\mu$ s) under the set conditions of V1 = 3.5 V, V2 = 0 V.

#### 8. 2 Active "H"

The overcurrent 3 detection delay time ( $t_{DIOV3}$ ) is the time period from when the voltage V2 exceeds  $V_{DIOV3}$  to when  $V_{DO}$  goes to "H", after V2 is increased to 1.6 V instantaneously (within 10  $\mu$ s) under the set conditions of V1 = 3.5 V, V2 = 0 V.



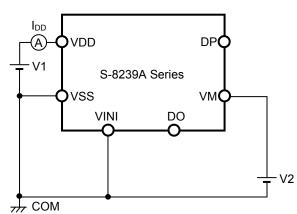
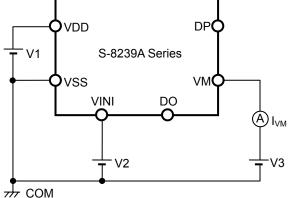


Figure 5 Test Circuit 2



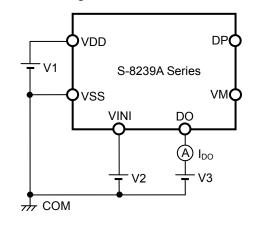


Figure 6 Test Circuit 3

Figure 7 Test Circuit 4

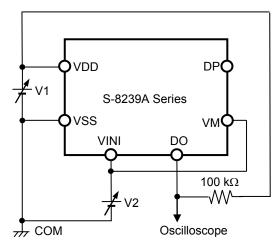


Figure 8 Test Circuit 5

## Operation

#### 1. Normal status

The S-8239A Series monitors the voltage between the VINI pin and the VSS pin to control discharging. When the VINI pin voltage is equal to or lower than the overcurrent 1 detection voltage ( $V_{DIOV1}$ ), the DO pin becomes "High-Z" (Active "L") or  $V_{SS}$  potential (Active "H"). This status is called the normal status.

Caution When a battery is connected for the first time, the S-8239A Series may not be in the normal status. In this case, short the VM pin and VSS pin or connect the charger. The S-8239A Series then becomes the normal status.

### 2. Overcurrent status (Overcurrent 1, overcurrent 2, overcurrent 3)

When a battery is in the normal status, if the VINI pin voltage is equal to or higher than the overcurrent detection voltage because the discharge current is equal to or higher than the specified value and the status continues for the overcurrent detection delay time or longer, the DO pin becomes  $V_{SS}$  potential (Active "L") or "High-Z" (Active "H"). This status is called the overcurrent status. The overcurrent status is retained when the voltage between the VDD pin and the VM pin is equal to or lower than the overcurrent release voltage ( $V_{RIOV}$ ).

In the overcurrent status, the VM pin and VSS pin are shorted by the internal resistor between the VM pin and the VSS pin ( $R_{VMS}$ ) in the S-8239A Series. However, the VM pin is at  $V_{DD}$  potential due to the external load as long as the external load is connected. When the external load is disconnected completely, the VM pin returns to  $V_{SS}$  potential. The overcurrent status is released when the voltage between the VDD pin and the VM pin is equal to or higher than  $V_{RIOV}$ .

#### 3. UVLO status

The S-8239A Series includes a UVLO (under voltage lock out) function to prevent the IC malfunction due to the decrease of the battery voltage when detecting the overcurrent. When the battery voltage in the normal status is equal to or lower than the UVLO detection voltage ( $V_{UVLO}$ ) and the status continues for the UVLO detection delay time ( $t_{UVLO}$ ) or longer, the DO pin becomes  $V_{SS}$  potential (Active "L") or "High-Z" (Active "H"). This status is called the UVLO status.

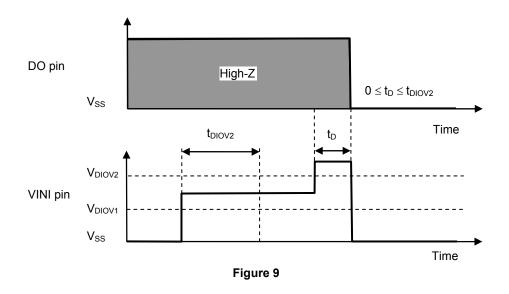
In the UVLO status, the VM pin and VSS pin are shorted by  $R_{VMS}$  between the VM pin and the VSS pin in the S-8239A Series.

After that, the UVLO status is released if the battery voltage becomes equal to or higher than V<sub>UVLO</sub>.

## 4. Delay circuit

The detection delay times are determined by dividing a clock of approximately 3.5 kHz with the counter.

**Remark** The overcurrent 2 detection delay time  $(t_{DIOV2})$  starts when the overcurrent 1 detection voltage  $(V_{DIOV1})$  is detected. When the overcurrent 2 detection voltage  $(V_{DIOV2})$  is detected over  $t_{DIOV2}$  after the detection of  $V_{DIOV1}$ , the S-8239A Series becomes the overcurrent status within  $t_{DIOV2}$  from the time of detecting  $V_{DIOV2}$ .



## 5. DP pin

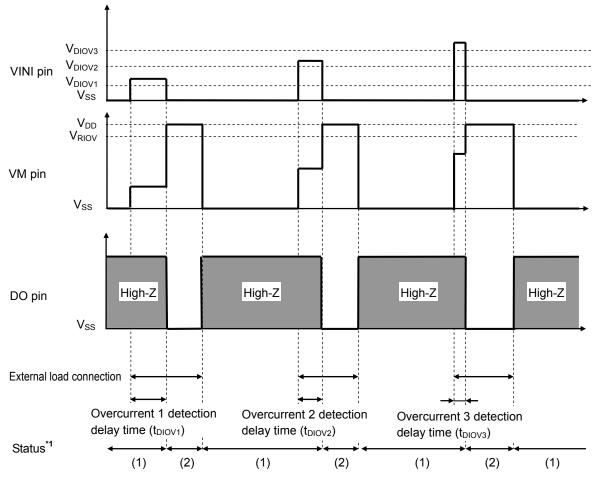
The DP pin is a test pin for delay time measurement and it should be open in the actual application. If a capacitor whose capacitance is 1000 pF or more or a resistor whose resistance is 1  $M\Omega$  or less is connected to this pin, error may occur in the delay times or in the detection voltages.

## **■** Timing Charts

## 1. Overcurrent detection

### 1. 1 Active "L"

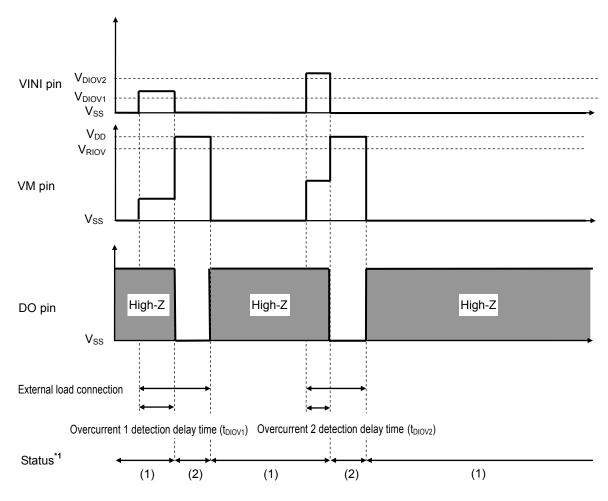
1. 1. 1 Overcurrent 3 detection function "available"



- \*1. (1): Normal status
  - (2): Overcurrent status

Figure 10

### 1. 1. 2 Overcurrent 3 detection function "unavailable"

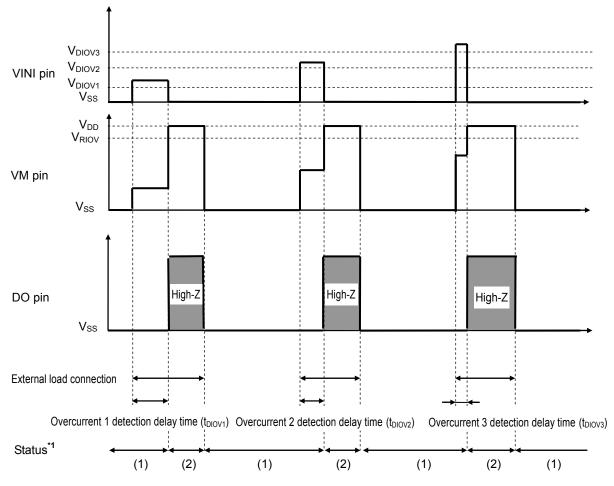


- \*1. (1): Normal status
  - (2): Overcurrent status

Figure 11

### 1. 2 Active "H"

## 1. 2. 1 Overcurrent 3 detection function "available"

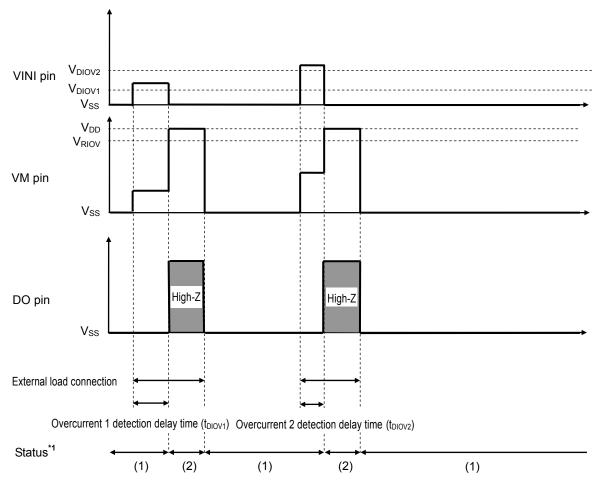


### \*1. (1): Normal status

(2): Overcurrent status

Figure 12

### 1. 2. 2 Overcurrent 3 detection function "unavailable"



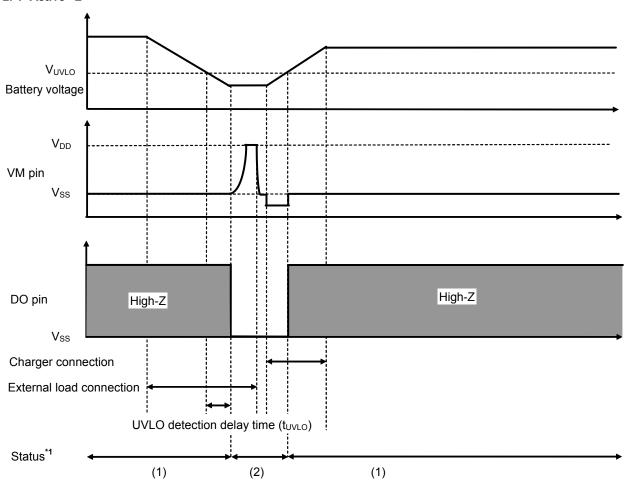
\*1. (1): Normal status

(2): Overcurrent status

Figure 13

## 2. UVLO detection

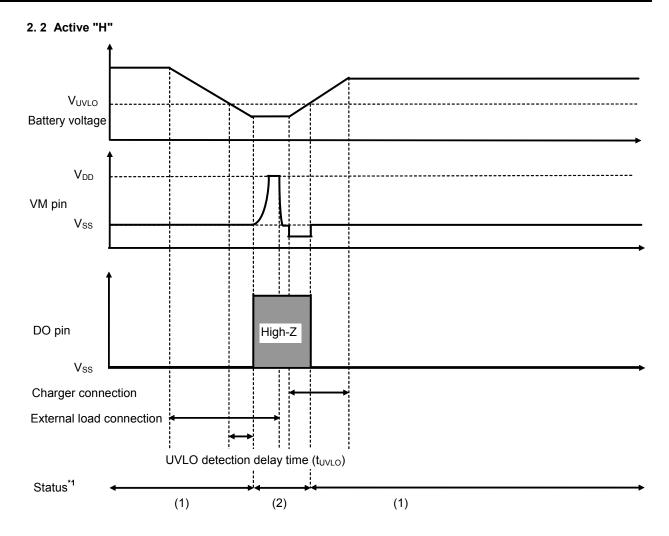
## 2. 1 Active "L"



\*1. (1): Normal status (2): UVLO status

**Remark** The charger is assumed to charge with a constant current.

Figure 14



\*1. (1): Normal status

(2): UVLO status

**Remark** The charger is assumed to charge with a constant current.

Figure 15

## ■ 5-serial-cell Protection Circuit Examples

**Figure 16** and **Figure 17** show the 5-serial-cell protection circuit examples used by the S-8239A Series and the S-8225A Series. Contact our sales office when using the circuit other than the following protection circuit examples.

#### 1. Active "L"

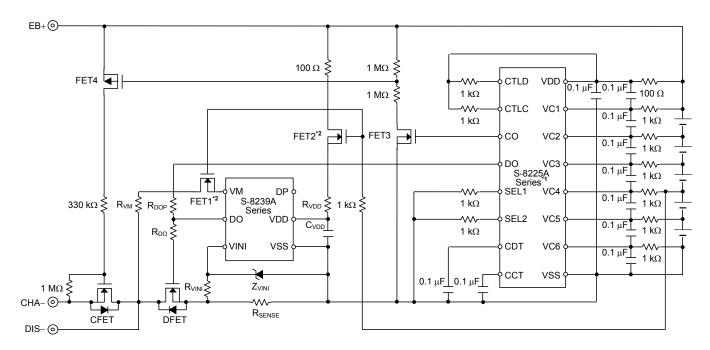


Figure 16

## 2. Active "H"

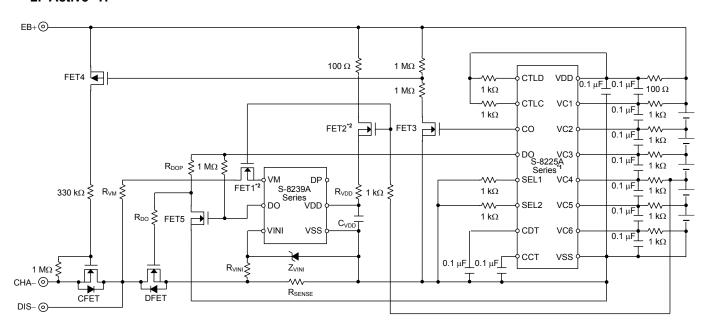


Figure 17

**Table 7 Constants for External Components** 

Symbol	Min.	Тур.	Max.	Unit
R <sub>VDD</sub>	300	470	1000	Ω
R <sub>VINI</sub>	1	_	_	kΩ
R <sub>SENSE</sub>	0	_	_	mΩ
R <sub>VM</sub>	1	5.1	51	kΩ
R <sub>DO</sub> *3	_	5.1	_	kΩ
R <sub>DOP</sub>	330	510	2000	kΩ
$C_{VDD}$	0.022	0.1	1	μF

<sup>\*1.</sup> Refer to the data sheet of the S-8225A Series for the recommended value for external components of the S-8225A Series.

### Caution 1. The above constants may be changed without notice.

- 2. The example of connection shown above and the constants do not guarantee proper operation. Perform thorough evaluation using the actual application to set the constant.
- 3. The DP pin should be open.

<sup>\*2.</sup> Use the products with the same model number for FET1 and FET2.

<sup>\*3.</sup> Set up the optimal constant according to the FET in use.

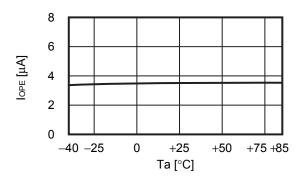
## ■ Precautions

- The application conditions for the input voltage, output voltage, and load current should not exceed the package power dissipation.
- Do not apply an electrostatic discharge to this IC that exceeds the performance ratings of the built-in electrostatic protection circuit.
- ABLIC Inc. claims no responsibility for any and all disputes arising out of or in connection with any infringement by products including this IC of patents owned by a third party.

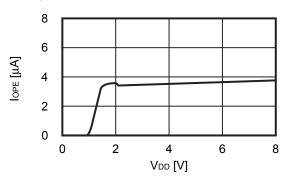
## ■ Characteristics (Typical Data)

## 1. Current consumption

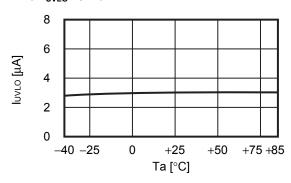
1.1 I<sub>OPE</sub> vs. Ta



1. 2  $I_{OPE}$  vs.  $V_{DD}$ 

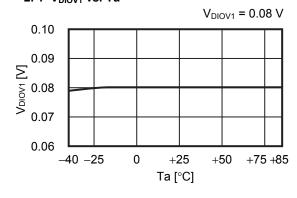


1. 3 I<sub>UVLO</sub> vs. Ta

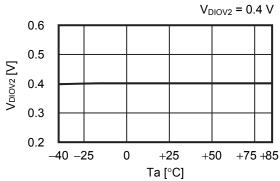


## 2. Overcurrent detection / release voltage, UVLO function and delay times

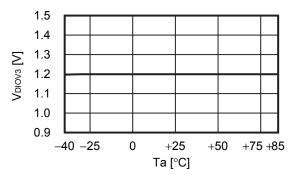
2. 1 V<sub>DIOV1</sub> vs. Ta



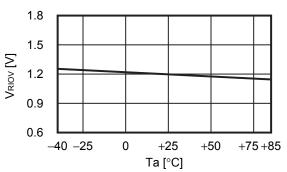
2. 2 V<sub>DIOV2</sub> vs. Ta



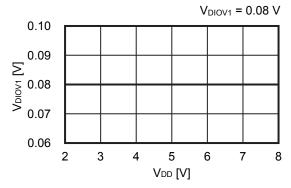
2. 3 V<sub>DIOV3</sub> vs. Ta



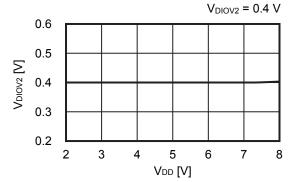
2. 4  $\,V_{RIOV}\,vs.\,Ta$ 



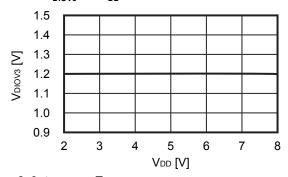
### 2. 5 $V_{\text{DIOV1}}$ vs. $V_{\text{DD}}$



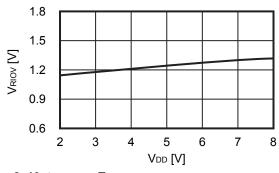
### 2. 6 $V_{\text{DIOV2}}$ vs. $V_{\text{DD}}$



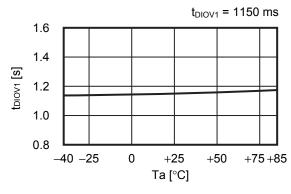
### 2. 7 $V_{DIOV3}$ vs. $V_{DD}$



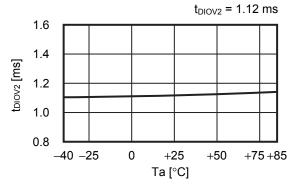
2. 8 V<sub>RIOV</sub> vs. V<sub>DD</sub>



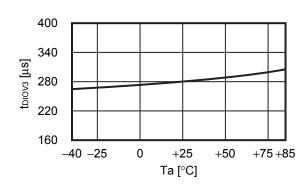
## 2. 9 $t_{\text{DIOV1}}$ vs. Ta



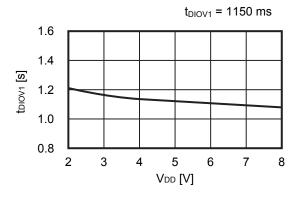
2. 10 t<sub>DIOV2</sub> vs. Ta



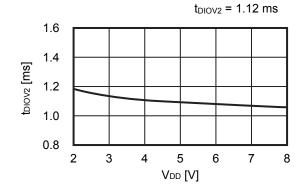
### 2. 11 t<sub>DIOV3</sub> vs. Ta



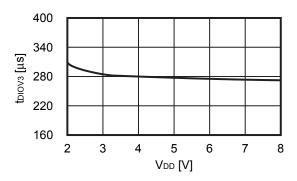
2. 12 t<sub>DIOV1</sub> vs. V<sub>DD</sub>



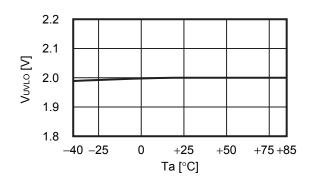
2. 13  $t_{\text{DIOV2}}$  vs.  $V_{\text{DD}}$ 



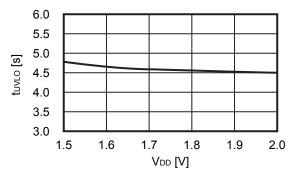
2. 14 t<sub>DIOV3</sub> vs. V<sub>DD</sub>



2. 15  $V_{UVLO}$  vs. Ta

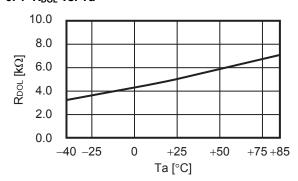


2. 16 t<sub>UVLO</sub> vs. V<sub>DD</sub>



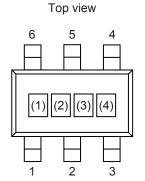
## 3. Output Resistance

3. 1 R<sub>DOL</sub> vs. Ta



# ■ Marking Specification

## 1. SOT-23-6

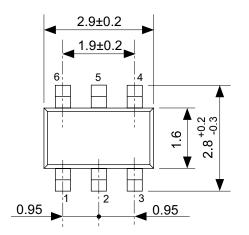


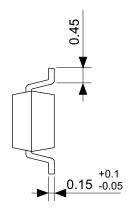
(1) to (3): Product code (Refer to **Product name vs. Product code**) (4):

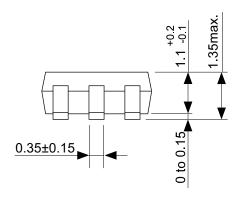
Lot number

## Product name vs. Product code

Product Name	Product Code			
Product Name	(1)	(2)	(3)	
S-8239AAA-M6T1U	3	S	Α	
S-8239AAB-M6T1U	3	S	В	
S-8239AAC-M6T1U	3	S	С	
S-8239AAD-M6T1U	3	S	D	
S-8239AAE-M6T1U	3	S	Е	
S-8239AAF-M6T1U	3	S	F	
S-8239AAG-M6T1U	3	S	G	
S-8239AAH-M6T1U	3	S	Н	
S-8239AAI-M6T1U	3	S	I	
S-8239AAJ-M6T1U	3	S	J	
S-8239AAK-M6T1U	3	S	K	

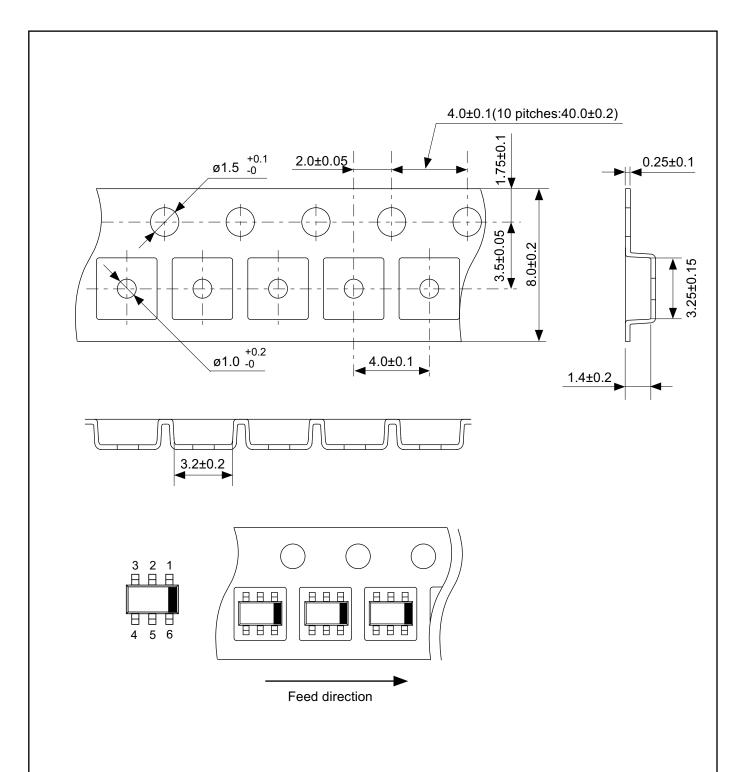






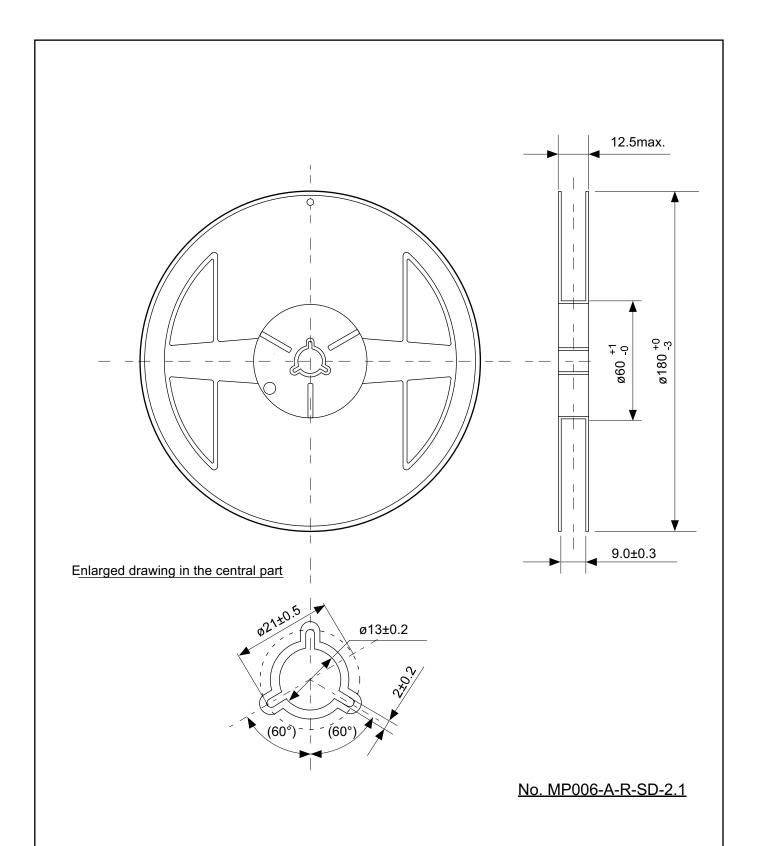
# No. MP006-A-P-SD-2.1

TITLE	SOT236-A-PKG Dimensions		
No.	MP006-A-P-SD-2.1		
ANGLE	<b>\$</b> =3		
UNIT	mm		
ABLIC Inc.			



## No. MP006-A-C-SD-3.1

TITLE	SOT236-A-Carrier Tape		
No.	MP006-A-C-SD-3.1		
ANGLE			
UNIT	mm		
ABLIC Inc.			



TITLE	SOT236-A-Reel				
No.	MPC	06-A-R-SI	D-2.1		
ANGLE		QTY 3,000			
UNIT	mm				
ABLIC Inc.					

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  - The entire system must be sufficiently evaluated and applied on customer's own responsibility.
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